TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7W53FU, TC7W53FK

2-Channel Multiplexer/Demultiplexer

The TC7W53 is a high speed C^2MOS Analog Multiplexer/ Demultiplexer fabricated with silicon gate C^2MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the C^2MOS low power dissipation. The TC7W53 has a 2 channel configuration.

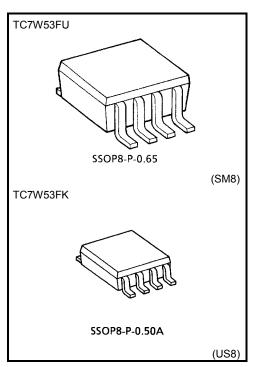
The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal ($V_{\rm CC}-V_{\rm EE}$) can then be switched by the small logical amplitude ($V_{\rm CC}-G_{\rm ND}$) control signal.

For example, in the case of $V_{\rm CC}=5$ V, GND=0 V, $V_{\rm EE}=-5$ V, signals between -5 V and +5 V can be switched from the logical circuit with a signal power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuit with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

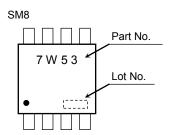
Features

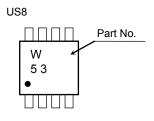
- High speed: $t_{pd} = 15 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$, $V_{EE} = 0 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Low ON resistance: RON = 50Ω (typ.) at VCC-VEE = 9 V
- High degree of linearity: THD = 0.02% (typ.) at V_{CC}-V_{EE} =9 V
- Pin and function compatible with TC4W53



Weight SSOP8-P-0.65: 0.02 g (typ.) SSOP8-P-0.50A: 0.01 g (typ.)

Marking





Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	–0.5 to 7	V	
Supply voltage range	V _{CC} – V _{EE}	−0.5 to 13	V	
Control input voltage	V _{IN}	-0.5 to $V_{CC} + 0.5$	V	
Switch I/O voltage	V _{I/O}	V_{EE} -0.5 to V_{CC} + 0.5	V	
Control input diode current	Ick	±20	mA	
I/O diode current	I _{IOK}	±20	mA	
Switch through current	Ι _Τ	±25	mA	
DC V _{CC} /GND current	Icc	±25	mA	
Douger dissination	D-	300 (SM8)	mW	
Power dissipation	P _D	200 (US8)	11100	
Storage temperature range	T _{stg}	-65 to 150	°C	
Lead temperature (10 s)	TL	260	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

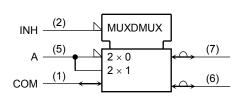
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Truth Table

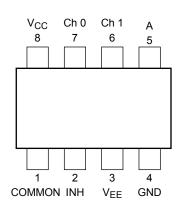
Contro	l Input	On Channel
INH	Α	On Channel
L	L	Ch 0
L	Н	Ch 1
Н	Х	None

X: Don't care

Logic Symbol

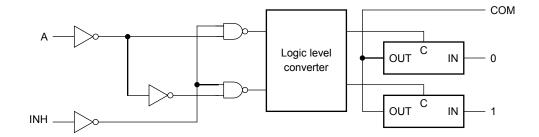


Pin Assignment (top view)





Logic Diagram



Operating Ranges

Characteristics	Symbol	Rating	Unit	
	V _{CC}	2 to 6		
Supply voltage	V _{EE}	−6 to 0	V	
	V _{CC} – V _{EE}	2 to 12		
Control input voltage	V _{IN}	0 to V _{CC}	V	
Switch I/O voltage	V _{I/O}	V _{EE} to V _{CC}	٧	
Operating temperature range	T _{opr}	-40 to 85	°C	
		0 to 1000 (V _{CC} = 2.0 V)		
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns	
		0 to 400 (V _{CC} = 6.0 V)		

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Electrical Characteristics

DC Electrical Characteristics

Characteristics Symbol Test Condition		Test Condition	ition		Ta = 25°C			Ta = -40 to 85°C		Unit			
		-,			,	V _{EE} (V)	V _{CC} (V)	Min	Тур.	Max	Min	Max	
			_	2.0	1.5	_		1.5	_				
	High level	V _{IHC}	_	_	4.5	3.15	_		3.15	_	V		
Control input				_	6.0	4.2	_		4.2	_			
voltage				_	2.0		_	0.5		0.5	V		
	Low level	V _{ILC}	_	_	4.5		_	1.35		1.35			
				_	6.0		_	1.8		1.8			
			V _{IN} = V _{ILC} or V _{IHC}	GND	4.5		85	180		225			
			$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5		55	120		150			
			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0		50	100		125			
ON resistance		R _{ON} $V_{IN} = V_{ILC} \text{ or } V_{IHC}$	GND	2.0	_	150	_	_	_	Ω			
				GND	4.5	_	70	150	_	190			
	$V_{I/O} = V_{CC}$ or V_{EE} $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5		50	100		125] 				
				-6.0	6.0		45	80	_	100			
Difference of C)N		V _{IN} = V _{ILC} or V _{IHC}	GND	4.5		10	30	_	35	Ω		
resistance bety		ΔR _{ON}	$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5	_	5	12	_	15			
switches			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0		5	10	_	12			
Input/output lea	akage		V _{OS} = V _{CC} or GND	GND	6.0	_	_	±60	_	±600			
current (switch		l _{OFF}	$V_{IS} = GND \text{ to } V_{CC}$ $V_{IN} = V_{ILC} \text{ or } V_{IHC}$	-6.0	6.0	_	_	±100	_	±1000	nA		
Switch input le	akage		V _{OS} = V _{CC} or GND	GND	6.0		_	±60	_	±600	- 0		
current (switch on outp	out open)	l _{IZ}	V _{IN} = V _{ILC} or V _{IHC}	-6.0	6.0	_	_	±100	_	±1000	nA		
Control input c	urrent	I _{IN}	$V_{IN} = V_{CC}$ or GND	GND	6.0	_	_	±0.1	_	±1.0	μΑ		
Quiescent sur	alv aurrant	l	V V or CND	GND	6.0	_	_	4	_	40	^		
Quiescent supply current	current I_{CC} $V_{IN} = V_{CC}$ or GND	-6.0	6.0			8	_	80	μА				



AC Electrical Characteristics ($C_L = 50 \text{ pF}$, input $t_r = t_f = 6 \text{ ns}$, GND = 0 V)

Characteristics	Symbol	Test Condition			-	Ta = 25°C			Ta = -40 to 85°C	
		rest condition	V _{EE} (V)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
			GND	2.0	_	25	60	_	75	ns
Phase difference between	φΙ/О		GND	4.5		6	12	_	15	
input and output	ψι/Ο	_	GND	6.0		5	10		13	
			-4.5	4.5	_	4	_	_	_	
			GND	2.0		50	225		280	ns
Outrout analysis	t _{pZL}	D 4160	GND	4.5		14	45		56	
Output enable time	t _{pZH}	$R_L = 1 \text{ k}\Omega$	GND	6.0		12	38		48	
			-4.5	4.5		14	_	_	_	
	t _{pLZ} t _{pHZ}	$R_L = 1 \text{ k}\Omega$	GND	2.0	_	95	225	_	280	- ns
Output disable time			GND	4.5	_	30	45	_	56	
Output disable time			GND	6.0	_	26	38	_	48	
			-4.5	4.5	_	26	_	_	_	
Control input capacitance	C _{IN}	_	_	_	_	5	10	_	10	pF
Common terminal capacitance	C _{IS}	_	-5.0	5.0	_	11	20	_	20	pF
Switch terminal capacitance	C _{OS}	_	-5.0	5.0		7	15		15	pF
Feed through capacitance	C _{IOS}	_	-5.0	5.0		0.75	2	_	2	pF
Power dissipation capacitance	C _{PD}	(Note)	GND	5.0	_	67	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$



Analog Switch Characteristics (GND = 0 V, Ta = 25°C)

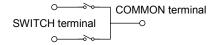
Characteristics	Symbol	Test Condition						Unit
		$V_{IN} = 4.0 \text{ Vp-p}$		-2.25	-2.25	0.025		
Sine wave distortion (T.H.D)	_	$R_L = 10 \text{ k}\Omega, C_L = 50 \text{ pF}$	V _{IN} = 8.0 Vp-p		-4.5	4.5	0.02	%
(1.n.u)		f _{IN} = 1 kHz	V _{IN} =	11 Vp-p	-6.0	6.0	0.018	0.018
				(Note1)	0.05	0.5	120	
				(Note2)	-2.25	-2.5	95	
Frequency response		Adjust V _{IN} voltage to obtain 0dBm at \ Increase F _{IN} until dB Meter reads –3c	-	(Note1)	4.5		190	
(switch ON)	t _{MAX}	$R_L = 50 \ \Omega, C_L = 10 \ pF$ (Note $f_{IN} = 1 \ MHz$, sine wave (Note		(Note2)	-4.5	4.5	150	MHz
				(Note1)		0.0	200	
				(Note2)	-6.0	6.0	190	
		V _{IN} is centered at (V _{CC} -V _{EE})/2. Adjust	st innut t	for OdBm	-2.25	2.25	-50	
Feed Through attenuation (switch OFF)	_	$R_L = 600 \Omega$, $C_L = 50 pF$		ioi oabiii	-4.5	-4.5	-50	dB
(* *** **		f _{IN} = 1 MHz, sine wave				6.0	-50	
Crosstalk				-2.25	2.25	60		
(control input to signal	_	$R_L = 600~\Omega,~C_L = 50~pF$ $f_{IN} = 1~MHz,~square~wave~(t_r = t_f = 6~ns)$			-4.5 -4.5	140	mV	
output)					-6.0	-6.0 6.0		
		Adjust V _{IN} to obtain 0dBm at input			2.25	2.25	-50	
Crosstalk (between any switches)	_	$R_L = 600 \Omega$, $C_L = 50 pF$			-4.5	-4.5	-50	dB
,		$f_{IN} = 1$ MHz, sine wave			6.0	6.0	-50	

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Note: These characteristics are determined by design of device.

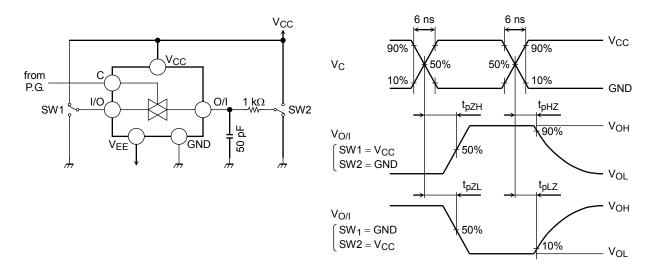
Note 1: Input COMMON terminal, and measure at SWITCH terminal.

Note 2: Input SWITCH terminal, and measure at COMMON terminal.

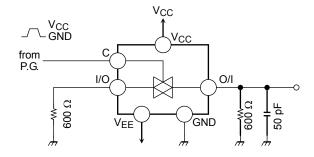


Switching Characteristics Test Circuits

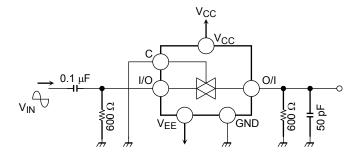
1. t_{pLZ} , t_{pHZ} , t_{pZL} and t_{pZH}



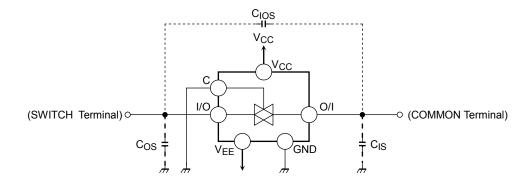
2. Cross Talk (control input-switch output) $f_{IN} = 1$ MHz, duty = 50% and $t_r = t_f = 6$ ns



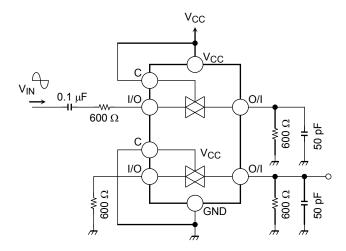
3. Feed Through Attenuation



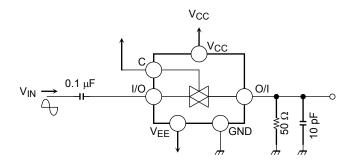
4. CIOS, CIS, COS



5. Cross Talk (between any two switches)



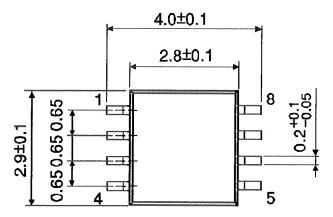
6. Frequency Response (switch ON)

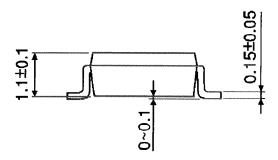


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Package Dimensions

SSOP8-P-0.65 Unit: mm





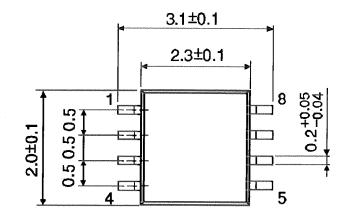
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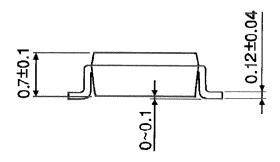
Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A







Weight: 0.01 g (typ.)

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